

<b>Notice of References Cited</b>	Application/Control No. <b>09/924,209</b>	Applicant(s)/Patent Under Reexam <b>Gunapala et al.</b>	
	Examiner <b>B. William Baumeister</b>	Art Unit <b>2815</b>	Page 1 of 1

**U.S. PATENT DOCUMENTS**

	Document Number Country Code-Number-Kind Code	Date MM-YYYY <sup>1</sup>	Name	Classification <sup>2</sup>	
A	5,384,469	1/1995	Choi	257	21
B					
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**FOREIGN PATENT DOCUMENTS**

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**NON-PATENT DOCUMENTS**

	Include, as applicable: Author, Title, Date, Publisher, Edition or Volume, Pertinent Pages
U	Chen et al., "Corrugated Quantum Well Infrared Photodetectors with Polyimide Planarization for Detector Array Applications," IEEE Transactions on Electron Devices, Vol. 45, No 7, July 1998, pp. 1431-1437.
V	Pan et al., "Normal incident infrared absorption from InGaAs/GaAs quantum dot superlattice," Electronics Letters, 29th August 1996, Vol. 32, No. 18, pp. 1726-1727.
W	Pan et al., "Strong normal-incidence infrared absorption and photo-current spectra from highly uniform (In,Ga)As/GaAs quantum dot structures," Electronics Letters, 14th May 1998, Vol. 34, No. 10, pp. 1019-1020.
X	Rokhinson et al., "Quantum grid infrared photodetectors," 1 February 1999, Applied Physics Letters, Vol. 74, No. 5, pp. 759-761.

\* A copy of this reference is not being furnished with this Office action. See MPEP § 707.05(a). <sup>1</sup> Dates in MM-YYYY format are publication dates. <sup>2</sup> Classifications may be U.S. or foreign.